Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-350-1470

Inclosure	Material:
Glass and	l metal
Overall L	ength:
0.550 incl	nes
Overall D	iameter:
0.487 incl	nes
Mounting	Facility Quantity:
1	
Mounting	y Method:
Threaded	stud
Features	Provided:
Hermetica	ally sealed case
Overall V	/idth Across Flats:
0.493 incl	nes
Thread S	ize:
0.190 incl	nes
Semicon	ductor Material:
Silicon	
Voltage F	Rating In Volts Per Characteristic:
200.0 rev	verse voltage, peak
Current F	Rating Per Characteristic:
25.00 mic	roamperes forward current, average peak
Maximun	n Operating Tempurature Per Measurement Point:
150.0 deg	rees celsius case
Thread S	eries Designator:
Unf	
Terminal	Type And Quantity:
2 tab, sol	der lug
Specifica	tion Data:
80131-rel	ease3944 professional/industrial association specification
Shelf Life	e:
N/a	
Unit Of N	leasure:
Demilitar	ization:
No	
Fiig:	
A110a0	